Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-193-8523

# Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

# **Overall Width:**

1.050 inches

## Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

40.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 0.25 amperes source cutoff current

#### **Power Rating Per Characteristic:**

6.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

1 case and 2 pin

#### **Specification Data:**

81349-mil-s-19500/523 government specification

### Shelf Life:

N/a

# Unit Of Measure:

# NSN 5961-01-193-8523

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

